

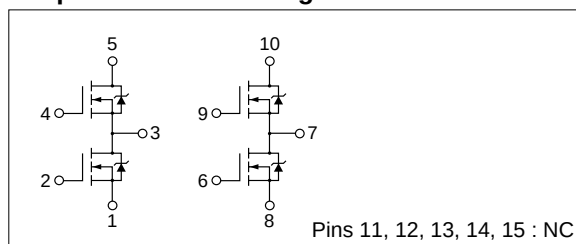
Absolute maximum ratings

(Ta=25°C)

Symbol	Ratings	Unit
V _{DSS}	60	V
V _{GSS}	±20	V
I _D	7	A
I _{D(pulse)}	15 (PW≤100μs, Du≤1%)	A
E _{AS} *	60	mJ
I _{AS}	7	A
P _T	4.8 (Ta=25°C, with all circuits operating, without heatsink) 35 (Tc=25°C, with all circuits operating, with infinite heatsink)	W
θ _{J-a}	26 (Junction-Air, Ta=25°C, with all circuits operating)	°C/W
θ _{J-c}	3.57 (Junction-Case, Tc=25°C, with all circuits operating)	°C/W
V _{ISO}	1000 (Between fin and lead pin, AC)	V _{rms}
T _{ch}	150	°C
T _{stg}	-40 to +150	°C

* : V_{DD}=20V, L=20mH, I_D=2A, unclamped, R_G=50Ω, see Fig. E on page 15.

■ Equivalent circuit diagram

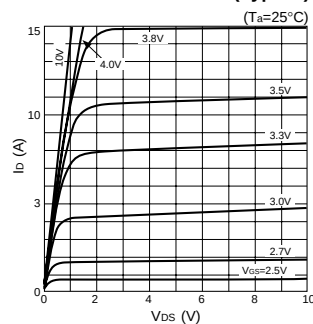
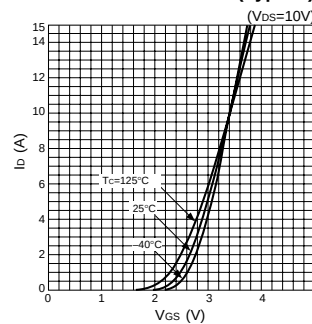
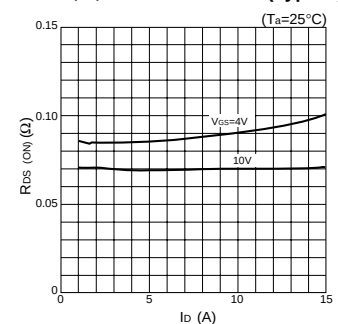
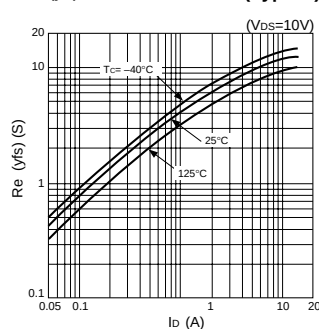
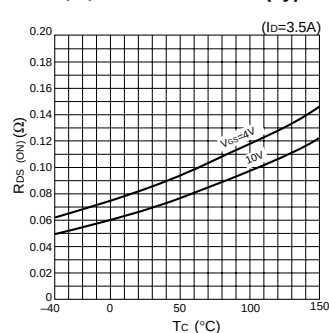
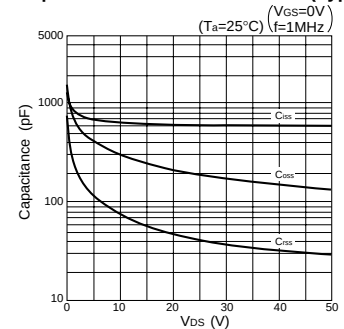
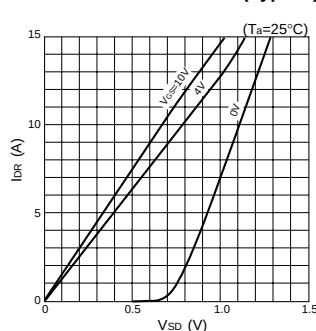


Electrical characteristics

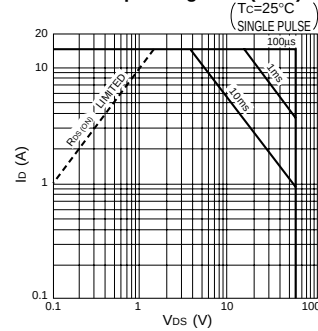
(Ta=25°C)

Symbol	Specification			Unit	Conditions
	min	typ	max		
V _{(BR)DSS}	60			V	I _D =100μA, V _{GS} =0V
I _{GSS}			±100	nA	V _{GS} =±20V
I _{DSS}			100	μA	V _{DS} =60V, V _{GS} =0V
V _{TH}	1.0		2.0	V	V _{DS} =10V, I _D =250μA
Re _(yfs)	6			S	V _{DS} =10V, I _D =3.5A
R _{DS(ON)}			0.1	Ω	V _{GS} =10V, I _D =3.5A
C _{iss}		660		pF	V _{DS} =10V, f=1.0MHz, V _{GS} =0V
C _{oss}		310		pF	
Cr _{ss}		75		pF	
td(on)		30		ns	I _D =3.5A, V _{DD} ≐20V, R _L =5.7Ω, V _{GS} =5V, see Fig. 3 on page 16.
tr		90		ns	
td(off)		140		ns	
tf		65		ns	
V _{SD}		1.1		V	I _{SD} =7A, V _{GS} =0V
t _{rr}		80		ns	I _{SD} =3.5A, di/dt=100A/μA

Characteristic curves

I_D-V_{DS} Characteristics (Typical)I_D-V_{GS} Characteristics (Typical)R_{DS(ON)}-I_D Characteristics (Typical)Re_(yfs)-I_D Characteristics (Typical)R_{DS(ON)}-T_C Characteristics (Typical)Capacitance-V_{DS} Characteristics (Typical)I_{DR}-V_{SD} Characteristics (Typical)

Safe Operating Area (SOA)

P_T-T_a Characteristics